NSN 5961-01-032-0466

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-032-0466 **Inclosure Material:** Glass **Overall Length:** Between 0.152 inches and 0.162 inches **Overall Diameter:** Between 0.115 inches and 0.125 inches **End Application:** Rcvr facsp anfsq-91 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0